FRIF IM.

- Designed for GSM BTS Transmitter Applications
- Low Insertion Loss
- 9.1 x 7.1 mm Surface-Mount Case
- Unbalanced Input and Output
- Complies with Directive 2002/95/EC (RoHS)



Absolute Maximum Ratings

Rating	Value	Units
Maximum Incident Power in Passband	+10	dBm
Max. DC voltage between any 2 terminals	30	VDC
Storage Temperature Range	-40 to +85	°C
Suitable for lead-free soldering - Max Soldering Profile	260°C	for 30 s

125.000 MHz SAW Filter

SF1082A



Electrical Characteristics

Characteristic			Min	Тур	Max	Units
ncy	f _C	1		125.000		MHz
Insertion Loss at fc	IL			6.0	8.0	dB
3 dB Passband	BW_3	1, 2	±275	±440		kHz
Amplitude Ripple over fc ±75 kHz					0.3	dB _{P-P}
Group Delay Variation over fc±75 kHz	GDV				100	ns _{P-P}
fc-7.5 to fc-6.0 and fc+6.0 to fc+7.5 MHz		1, 2, 3	20	40		dB
Ultimate				>40		UD
Operating Temperature Range		1	-40		+85	°C
3 dB Pa Amplitude Ripple over fc ± Group Delay Variation over fc± ejection fc-7.5 to fc-6.0 and fc+6.0 to fc+7		Insertion Loss at fc IL 3 dB Passband BW ₃ Amplitude Ripple over fc ±75 kHz Group Delay Variation over fc±75 kHz GDV fc-7.5 to fc-6.0 and fc+6.0 to fc+7.5 MHz Ultimate	Insertion Loss at fc IL 3 dB Passband BW ₃ 1, 2 Amplitude Ripple over fc ±75 kHz GDV Group Delay Variation over fc±75 kHz GDV fc-7.5 to fc-6.0 and fc+6.0 to fc+7.5 MHz I, 2, 3 Ultimate I	Insertion Loss at fc IL 3 dB Passband BW3 1, 2 ±275 Amplitude Ripple over fc ±75 kHz GDV 1, 2, 3 20 Group Delay Variation over fc±7.5 MHz I, 2, 3 20 Ultimate Insertion Insertion 10	Insertion Loss at fc IL 6.0 3 dB Passband BW3 1, 2 ±275 ±440 Amplitude Ripple over fc ±75 kHz GDV Group Delay Variation over fc±75 kHz GDV fc-7.5 to fc-6.0 and fc+6.0 to fc+7.5 MHz 1, 2, 3 20 40 Ultimate >40	Insertion Loss at fc IL 6.0 8.0 3 dB Passband BW3 1, 2 ±275 ±440 Amplitude Ripple over fc ±75 kHz 0.3 0.3 0.3 Group Delay Variation over fc±75 kHz GDV 100 100 fc-7.5 to fc-6.0 and fc+6.0 to fc+7.5 MHz 1, 2, 3 20 40 Ultimate >40 0.5 0.5

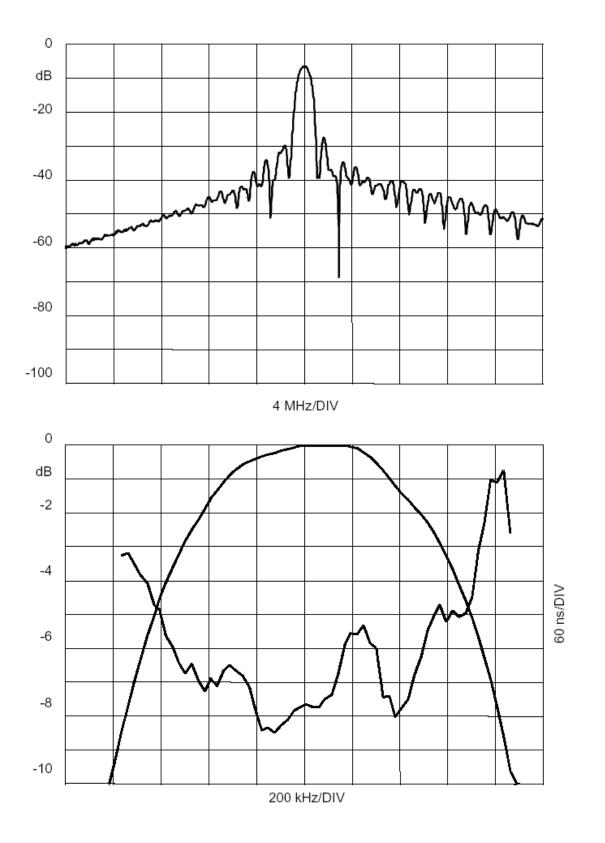
Impedance Matching to 50 Ω unbalanced	External L-C
Case Style	SM9171-10 9.1 x 7.1 mm Nominal Footprint
Lid Symbolization (XX = 2 character date code)	RFM SF1082A XX

Electrical Connections

Connection	Terminals
Port 1 Hot	1
Port 1 Gnd Return	4
Port 2 Hot	6
Port 2 Gnd Return	9
Case Ground	All others

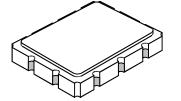
Notes:

- 1. Unless noted otherwise, all specification apply over the operating temperature range with filter soldered to the specified demonstration board with impedanced matching to 50 Ω network analyzer.
- 2. Unless noted otherwise, all frequency specifications are referenced to the nominal center frequency, fc.
- 3. Rejection is measured as attenuation below the minimum IL point in the passband. Rejection in final user application is dependent on PCB layout and external impedance matching design. See Application Note No. 42 for details.
- 4. "LRIP" or "L" after the part number indicates "low rate initial production" and "ENG" or "E" indicates "engineering prototypes."
- 5. The design, manufacturing process, and specifications of this filter are subject to change.
- 6. Either Port 1 or Port 2 may be used for either input or output in the design. However, impedances and impedance matching may vary between Port 1 and Port 2, so that the filter must always be installed in one direction per the circuit design.
- 7. US and international patents may apply.
- 8. RFM, stylized RFM logo, and RF Monolithics, Inc. are registered trademarks of RF Monolithics, Inc.
- 9. Electrostatic Sensitive Device. Observe precautions for handling.



SM9171-10 Case

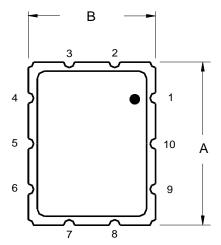
10-Terminal Ceramic Surface-Mount Case 9.1 x 7.1 mm Nominal Footprint

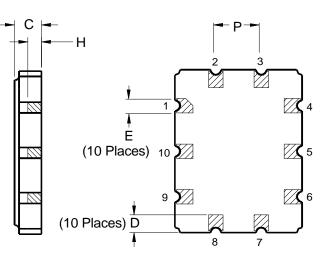


Case Dimensions							
Dimension		mm			Inches		
	Min	Nom	Max	Min	Nom	Max	
A	8.86	9.09	9.40	0.349	0.358	0.370	
В	6.88	7.11	7.40	0.271	0.280	0.291	
С		1.91	2.00		0.075	0.079	
D		0.99			0.039		
E		0.79			0.031		
Н		1.0			0.039		
Р		2.54			0.100		

	Materials						
Solder Pad Termination	Au plating 30 - 60 μinches (76.2-152 μm) over 80- 200 μinches (203-508 μm) Ni.						
Lid	Fe-Ni-Co Alloy Electroless Nickel Plate (8-11% Phosphorus) 100-200 µinches Thick						
Body	Al ₂ O ₃ Ceramic						
Pb Free							

Electrical Connections						
	Connection	Terminals				
Port 1	Input or Return	6				
	Return or Input	5				
Port 2	Output or Return	1				
	Return or Output	10				
	Ground	All others				
Single Ended Operation		Return is ground				
Differe	ntial Operation	Return is hot				





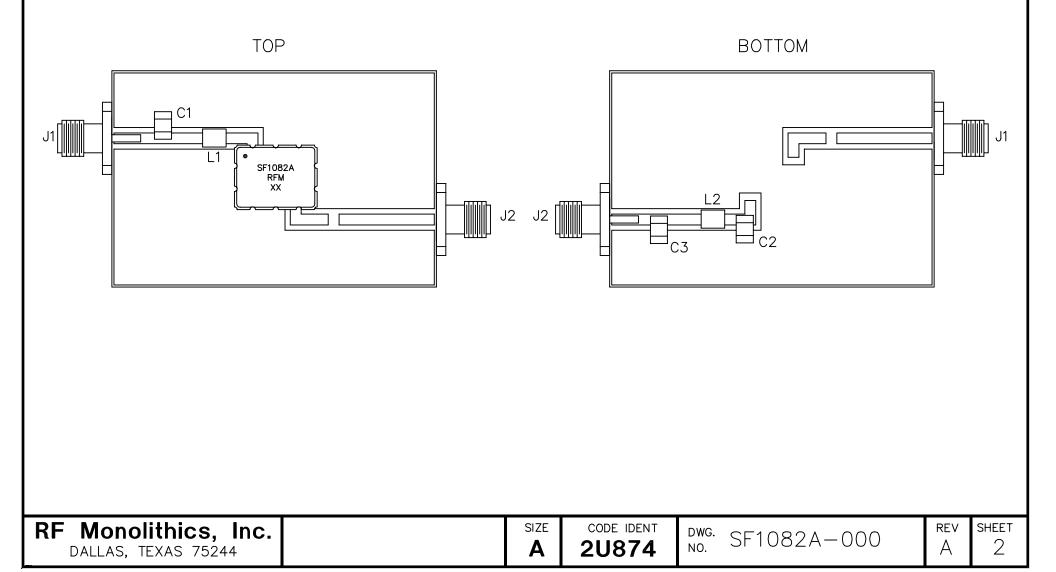
			REV	ECN NO.		APP/DATE
INPUT J1 J L C1 J L C1 J J L C1 J L C1	L1 150nH 2 3 4	10 9 D.U.T. 8 7 5 6	A	● C2	INITIAL RELEASE $L2 \qquad OUTPUT$ $150nH \qquad J2$ $L2 \qquad C3$ J= 33pF	
DRAWN BY/DATE: J.J. LAYTO RF Monolithics, Inc. DALLAS, TEXAS 75244	N 01/15/98 checked/approved		A ODE ID 2087	ENT DV	DIAGRAM, SF1082A-D M ^{G.} SF1082A-000	EMO rev sheet A 1/3

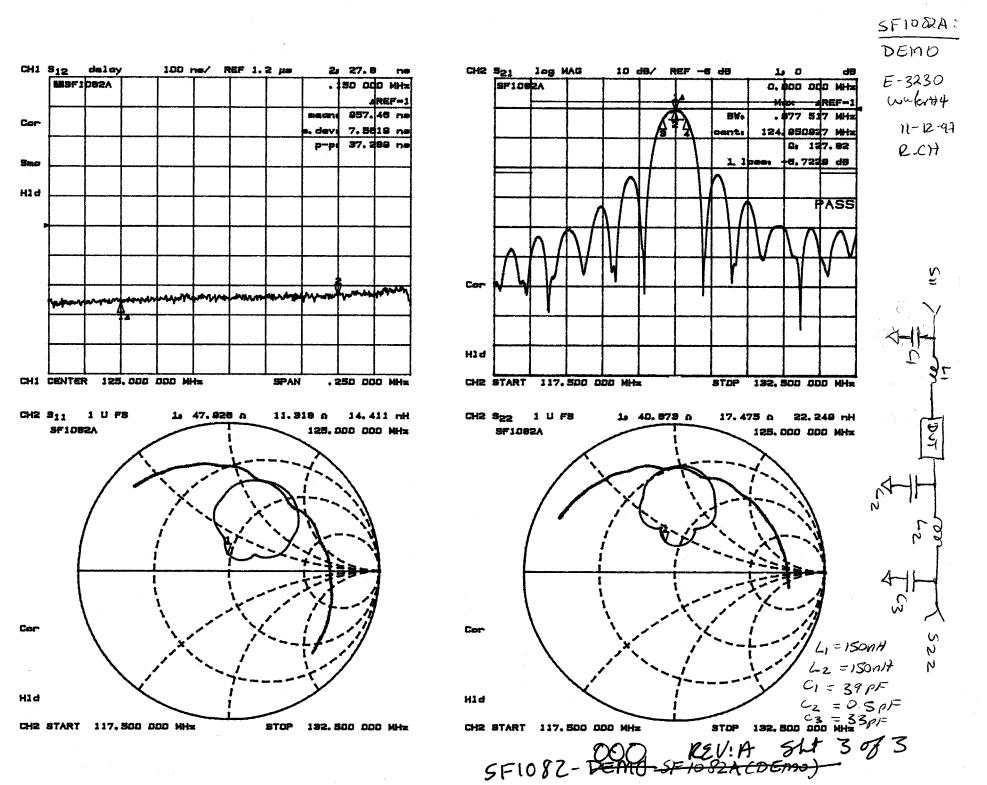
NOTES:

1. SOLDER MOUNT COMPONENTS TO PCB.

2. NOTE PROPER ORIENTATION OF INDUCTORS IS 90° TO EACH OTHER.

3. COMPONENT VALUES MAY NEED TO BE TRADED FOR SLIGHTLY HIGHER OR LOWER VALUES DUE TO TOLERANCE LEVELS OF EACH INDIVIDUAL COMPONENT.





BILL OF MATERIALS

PART IDENTIFIER	DESCRIPTION 1	DESCRIPTION 2	<u>QTY/ASSY</u>	REFERENCE DESCRIPTION
SF1082A-DEMO	DEMO BOARD,SF1082A			
SF1082A-000	ASSY DIAGRAM, DEMO BOARD,	SF1082A	0	
400-1389-001	PCB,DEMO BD,9 X 7		1.0000	CHAS1
500-0003-390	CAP,CHIP,NPO,39(J),STD		1.0000	C 1
500-0013-005	CAP,CHIP,NPO,0.5(E),STD	0805	1.0000	C 2
500-0003-330	CAP,CHIP,NPO,33(J),STD		1.0000	C 3
500-0583-151	IND,CHIP,0805CS,150NH		2.0000	L 1,2

in p liter liter	SIZE	FSCM NO.	DWG NO.	
FKIP IMI.	Α	2U874	S	F1082A-DEMO
SCALE NONE	W/O or EC	^ℕ 6254	rev A	SHEET 1 OF 2

	-			REV F	IISTORY							
REV	ECN	DATE				D	ESCRIPTION					
А	6254	12/17/97	INITIAL RELEAS	SE								
	-											
				B iriP II		SIZE	FSCM NO.	DWG NO.				
				II "KII	"M.	Α	2U874		S	F1082A	-DEMC)
				SCALE	NONE	W/O or EC	^N 6254	REV	Α	SHEET	2 OF	2